MOSFETs Silicon N-Channel MOS (U-MOSVI-H)

# TK40P04M1

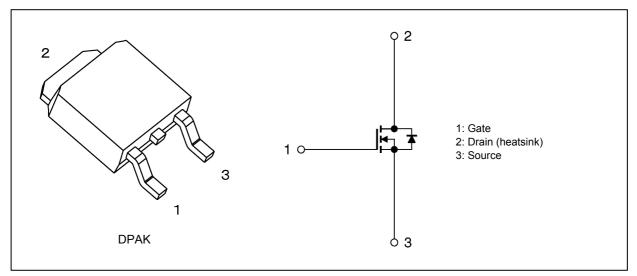
#### 1. Applications

- Switching Voltage Regulators
- Motor Drivers

#### 2. Features

- (1) High-speed switching
- (2) Low gate charge:  $Q_{SW} = 7.4 \text{ nC}$  (typ.)
- (3) Low drain-source on-resistance:  $R_{DS(ON)} = 8.5 \text{ m}\Omega \text{ (typ.)} (V_{GS} = 10 \text{ V})$
- (4) Low leakage current:  $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 40 \ V)$
- (5) Enhancement mode:  $V_{th}$  = 1.3 to 2.3 V ( $V_{\rm DS}$  = 10 V,  $I_{\rm D}$  = 0.2 mA)

#### 3. Packaging and Internal Circuit



#### 4. Absolute Maximum Ratings (Note) ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics			Rating	Unit
Drain-source voltage		V <sub>DSS</sub>	40	V
Gate-source voltage		V <sub>GSS</sub>	±20	
Drain current (DC)	(Note 1)	I <sub>D</sub>	40	А
Drain current (pulsed)	(Note 1)	I <sub>DP</sub>	120	
Power dissipation $(T_c = 2)$	25°C)	PD	47	W
Single-pulse avalanche energy	(Note 2)	E <sub>AS</sub>	41	mJ
Avalanche current		I <sub>AR</sub>	40	A
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature		T <sub>stg</sub>	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R <sub>th(ch-c)</sub>	2.65	°C/W
Channel-to-ambient thermal resistance	R <sub>th(ch-a)</sub>	125	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V\_DD = 32 V, T\_ch = 25°C (initial), L = 20  $\mu$ H, R<sub>G</sub> = 25  $\Omega$ , I<sub>AR</sub> = 40 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

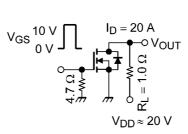
#### 6. Electrical Characteristics

#### 6.1. Static Characteristics (T<sub>a</sub> = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±20 V, $V_{DS}$ = 0 V	_	_	±0.1	μA
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = 40 V, V <sub>GS</sub> = 0 V	_	_	10	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	40	—	—	V
	V <sub>(BR)DSX</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = -20 V	25	_	_	
Gate threshold voltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.2 mA	1.3	_	2.3	
Drain-source on-resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 20 A	_	10.3	13.4	mΩ
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 20 A		8.5	11	

#### 6.2. Dynamic Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz		1920	_	pF
Reverse transfer capacitance	C <sub>rss</sub>	]		90	—	
Output capacitance	C <sub>oss</sub>		_	310	—	
Gate resistance	r <sub>g</sub>	$V_{DS}$ = 10 V, $V_{GS}$ = 0 V, f = 5 MHz	_	1.6	3.5	Ω
Switching time (rise time)	tr	See Figure 6.2.1.	_	20	—	ns
Switching time (turn-on time)	t <sub>on</sub>		_	27	—	
Switching time (fall time)	t <sub>f</sub>	]		18	_	
Switching time (turn-off time)	t <sub>off</sub>	]		63	—	



Duty  $\leq$  1%,  $t_W =$  10  $\mu s$ 

Fig. 6.2.1 Switching Time Test Circuit

#### 6.3. Gate Charge Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus	Qg	$V_{DD} \approx 32$ V, $V_{GS}$ = 10 V, $I_D$ = 40 A	_	29	_	nC
gate-drain)		$V_{DD} \approx 32$ V, $V_{GS}$ = 5 V, $I_D$ = 40 A	_	15	_	
Gate-source charge 1	Q <sub>gs1</sub>	$V_{DD} \approx 32$ V, $V_{GS}$ = 10 V, $I_D$ = 40 A	_	6.0	_	
Gate-drain charge	Q <sub>gd</sub>		_	4.7	_	
Gate switch charge	Q <sub>SW</sub>		_	7.4	_	

#### 6.4. Source-Drain Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed) (N	Note 3)	I <sub>DRP</sub>	—	_	_	120	А
Diode forward voltage		$V_{\text{DSF}}$	I <sub>DR</sub> = 40 A, V <sub>GS</sub> = 0 V	_	_	-1.2	V

Note 3: Ensure that the channel temperature does not exceed 150°C.

#### 7. Marking

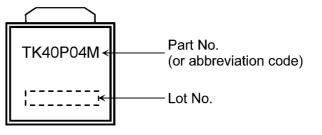
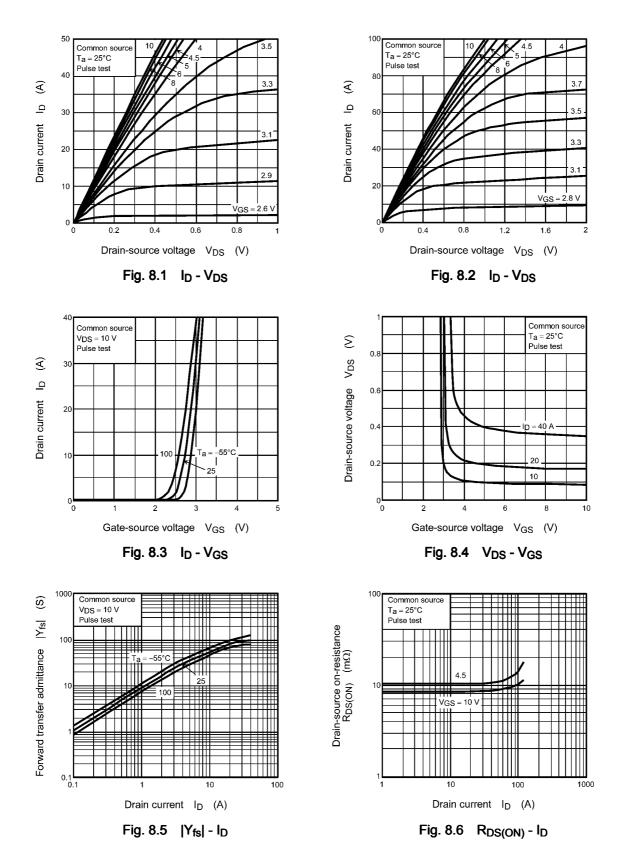
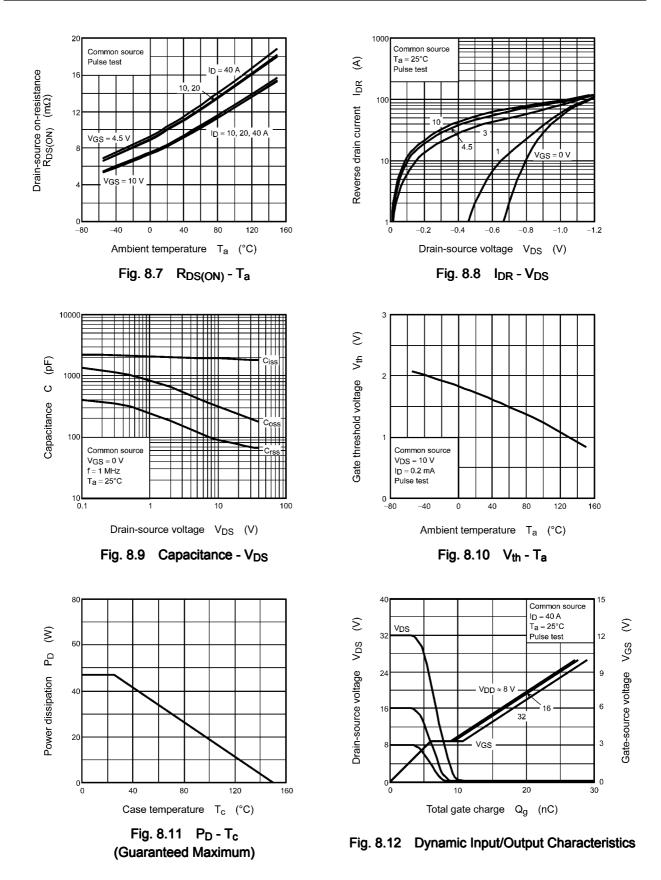
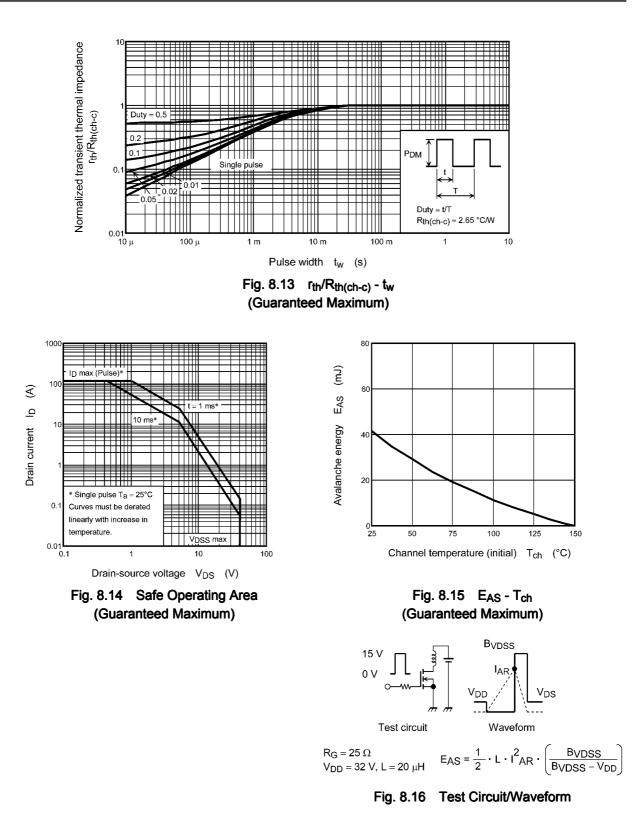


Fig. 7.1 Marking

#### 8. Characteristics Curves (Note)





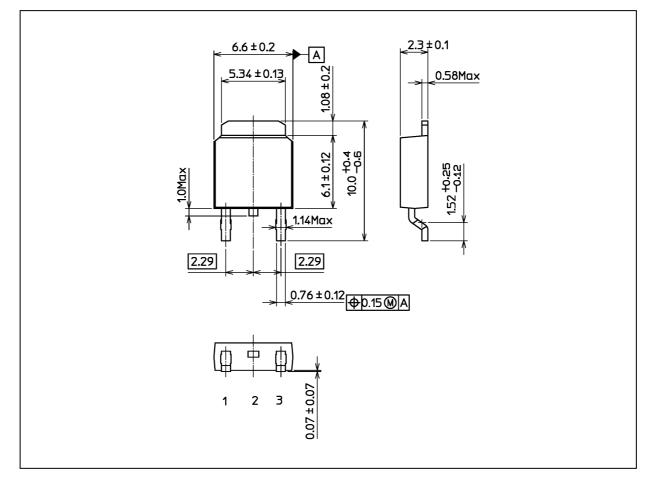


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

#### TK40P04M1

#### Package Dimensions

Unit: mm



Weight: 0.36 g (typ.)

	Package Name(s)
TOSHIBA: 2-7K1S	
Nickname: DPAK	

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